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# **Dual TMBS® (Trench MOS Barrier Schottky) Rectifier**

Ultra Low  $V_F = 0.39$  V at  $I_F = 5$  A





## ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	170 A			
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.57 V			
T <sub>J</sub> max.	150 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

### FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30D60C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	30	A	
	per diode		15		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	170	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

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ROHS COMPLIANT



V30D60C



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> (1)	0.47	-	V	
	I <sub>F</sub> = 7.5 A			0.51	-		
	I <sub>F</sub> = 15 A			0.60	0.70		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.38	-		
	I <sub>F</sub> = 7.5 A			0.44	-		
	I <sub>F</sub> = 15 A			0.57	0.65		
Reverse current per diode	V <sub>R</sub> = 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	1200	μA	
	v <sub>R</sub> = 60 v	T <sub>A</sub> = 125 °C		17	60	mA	

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V30D60C	UNIT	
Typical thermal resistance	per diode	R <sub>θJC</sub>	2.5		
	per device		1.7	°C/W	
	per device	R <sub>0JA</sub> (1)(2)	48		

#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V30D60C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V30D60CHM3_A/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

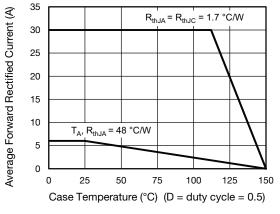


Fig. 1 - Forward Current Derating Curve

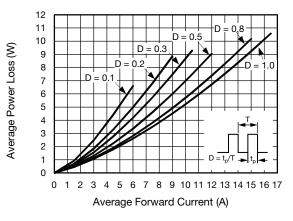
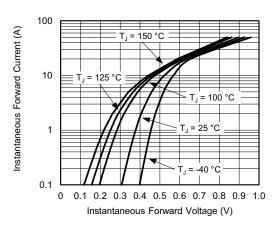


Fig. 2 - Forward Power Loss Characteristics Per Diode





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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

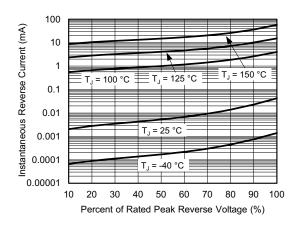


Fig. 4 - Typical Reverse Characteristics Per Diode

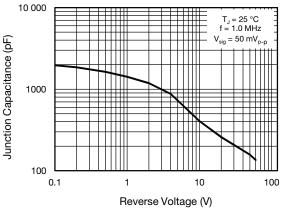


Fig. 5 - Typical Junction Capacitance Per Diode

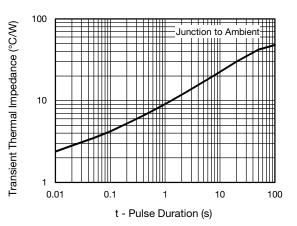
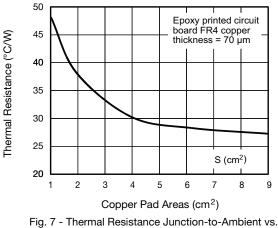


Fig. 6 - Typical Transient Thermal Impedance Per Diode



ig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

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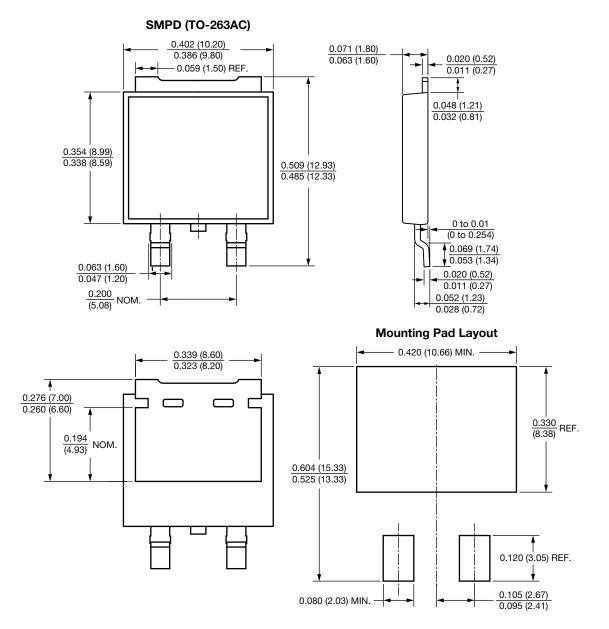
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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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